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Mechanism of surface treatments on carbon nanotube transparent conductive films by three different reagents

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Transparent conductive films (TCFs) were fabricated *via* a spray-coating method with a solution prepared by dispersing single-walled carbon nanotubes (SWCNTs) in deionized water with sodium dodecylbenzene sulfonate (SDBS) as surfactant. We explored the mechanism of HNO₃ treatment by treating TCFs with different reagents. After being treated with different concentrations of reagents by HNO₃, HCl, and NaNO₃ to lower the sheet resistance of TCFs, the properties of TCFs were further characterized by a UV-VIS spectrophotometer, a four-point probe method, atom force microscopy, X-ray photoelectron spectroscopy, and Raman spectroscopy. In this study, we conclude that the HNO₃ treatment results in a decrease in the sheet resistance of the TCFs due to the combined effect of acidity and oxidizability. The strong interaction of the strong acidity and strong oxidizing property of HNO₃ causes the SDBS to be removed. To further improve the film conductivity of the TCFs, the experimental conditions of the HNO₃ treatment were optimized.

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1. Introduction

Due to the rapid development of electronic equipment, the demand for transparent conductive films (TCFs) has become more and more urgent. More stringent requirements on the physical and chemical properties of conducting materials have to be put forward. To this goal, a lot of research regarding flexible TCFs has been carried out incorporating different conductive nanomaterials such as carbon nanomaterials,^{1,2} metallic nanowires,³ nanoparticles,⁴ and conductive polymers.⁵

Carbon nanotubes (CNTs) have attracted a lot of research attention due to their specific structure and excellent mechanical, optical and electrical properties,^{6,7} and thus have been used in diverse fields as transistors,⁸ storage devices,⁹ and optoelectronic devices.¹⁰ CNT incorporated transparent conductive films (CNT-TCFs) can be used in a flexible electroluminescent device because CNTs can also be introduced as a hole injection buffer layer on ITO to realize a high brightness organic light emitting diode (OLED).^{11,12} CNT-TCFs can be prepared by direct growth, solution deposition, spray coating, and vacuum filtration methods.¹³ Among them, spray coating is a commonly used preparation method, which has the advantage of low cost, simplicity, easy realization of large scale films and uniform film formation.¹⁴ Because of the large specific surface area in carbon

nanotubes, a strong van der Waals force among the nanotubes induces CNT entanglement and results in the formation of agglomerates. To solve this problem, a suitable surfactant is required in the preparation process of CNT dispersion. However, the tiny amount of surfactant present in the TCFs affects the conductivity due to its inherent insulating properties.^{15,16} Therefore, it is necessary to remove the surfactant by post-treatment in order to improve the conductivity of the CNT-TCFs. There are several post-processing methods for improving the conductivity of the CNT-TCFs without affecting the transmittance, such as immersion in HNO₃, H₂SO₄ or SOCl₂, and *p*-type and *n*-type doping of the CNTs.^{17–21} Compared to these methods, a very effective treatment of using HNO₃ is suggested. The purpose of this treatment is to remove the surfactants used for dispersing CNTs in solution and create a denser CNT film.²¹ However, it does not further explain what properties of HNO₃ reduce the sheet resistance of CNT-TCFs. The improvement in film transmittance and sheet resistance was attributed to the acidic properties instead of an oxidation effect. Therefore, in this study, we further explored the mechanism of HNO₃ treatment by treating CNT-TCFs with different reagents.

In this work, we prepared CNT-TCFs by spraying CNT solution on a polyethylene terephthalate (PET) substrate. The effects of different kinds of reagents, the concentrations of post-treatment reagents, and post-treating time on the electrical and optical properties of CNT-TCFs were investigated by versatile methods. In order to understand the effect of post-treatment by HNO₃, three reagents (HNO₃, HCl, and NaNO₃) were selected to post-treat the CNT-TCFs for comparison. HNO₃

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contains H^+ and NO_3^- , while NaNO_3 contains NO_3^- and HCl contains H^+ . These two reagents were chosen as a comparative study to understand the mechanism of HNO_3 treatment, and to explore which kinds of ions play an effective role to reduce the resistance of CNT-TCFs.

2. Experimental section

2.1 Preparation of a single-walled carbon nanotube solution

0.02 g single-walled carbon nanotubes (SWCNTs) with a purity of 90% were dispersed into 20 ml water by using 0.2 g sodium dodecylbenzene sulfonate (SDBS) as the dispersant. A concentration of 1 mg ml^{-1} of SWCNT solution was prepared and then ultrasonicated for 40 min. The solution was further ultrasonicated at 120 w for another 35 min in order to obtain a better dispersion of CNTs. The resulting homogeneous SWCNT dispersion was centrifuged at 8000 rpm for 15 min, and the supernatant was transferred to a clean beaker.^{15,22}

2.2 Preparation and characterization of the carbon nanotube conductive films

A PET film was cut to $5 \text{ cm} \times 5 \text{ cm}$ in size. Then the PET film was ultrasonicated in distilled water for one hour and then in ethanol for one hour. Subsequently, the PET film was dried with an air dryer. CNT-TCFs were prepared by spraying the SWCNT solution on the cleaned PET substrates. The temperature of the PET substrate was maintained at about 100°C for the solution to dry quickly. The dried CNT-TCFs were then immersed in distilled water for 20 min and then washed with distilled water 4 times. The effects of the three different reagents (HCl (38 wt%), HNO_3 (68 wt%), and a saturated solution of NaNO_3), the ratio of acid to water, the post-treatment time for removing the residual surfactants on the surface resistance and transmittance of CNT-TCFs were studied.

The transmittance of the CNT-TCFs was measured by a UV-VIS spectrophotometer at a wavelength of 550 nm, and the sheet resistance of the as-prepared and post-treatment CNT-TCFs was obtained by using the four-point probe method (Keithley 2700 multimeter) in sequence. The morphology of the CNT-TCFs was observed using a field emission scanning electron microscope (FE-SEM, HITACHI S-4800) and an atomic force microscope (AFM, Agilent-S5500). The surface changes were detected by X-ray photoelectron spectroscopy (XPS, ELMER PHI 5600, Al K α source). Raman spectra were used to characterize the change of CNTs *via* a DXR Raman microscope with a laser excitation wavelength of 532 nm.

3. Results and discussion

3.1 The effect of different reagents during post-treatment on sheet resistance and transmittance of the films

Sheet resistance and transmittance are found to be the most crucial factors dominating the performance of the CNT-TCFs. In order to enhance the conductivity, the CNT-TCFs were post-treated by three different reagents at the same concentration, which were HNO_3 solution, HCl solution and a saturated

solution of NaNO_3 , respectively. The sheet resistance and transmittance of CNT-TCFs were affected by the use of different reagents during post-treatment, as shown in Fig. 1.

In comparison with untreated CNT-TCFs, a higher sheet resistance was found for the CNT-TCFs after post-treatment by NaNO_3 . This suggested that the NO_3^- ion is incapable of removing the surfactant. The TCFs post-treated by a solution of either HCl or HNO_3 show a lower sheet resistance compared with the untreated CNT-TCFs, indicating that the acidic environment favors the removal of surfactants in CNT-TCFs. Moreover, the lowest sheet resistance was found for the CNT-TCFs treated with HNO_3 solution, which is consistent with a previous report.¹⁷ As TCFs were placed in the HNO_3 solution, the CNTs in the CNT-TCFs may undergo chemical oxidation during post-treatment by attachment of functional groups such as carboxyl groups. From this we believe that the H^+ in HNO_3 , that is the strong acidity, causes the non-conductive SDBS to be removed from the surface of the CNTs.

3.2 The effect of diluted nitric acid during post-treatment on sheet resistance and transmittance of films

The above results clearly demonstrate that the sheet resistance of the CNT-TCFs treated by an acidic solution of TCFs decreased significantly. To further improve the film conductivity of the TCFs, the experimental conditions with HNO_3 were optimized. The effects of post-treating time (from 0, 20, 40, to 60 min) and the ratio of acid to water (from 4 : 1, 6 : 1, to 8 : 1) on the sheet resistance and transmittance are presented in Fig. 3. As post-treating time increases to 60 min, the sheet resistance dramatically decreases.

As shown in Fig. 2, the sheet resistance and the transmittance decrease with HNO_3 treating time and ratio of HNO_3 to water simultaneously. The dramatic effect can be found for a certain HNO_3 treating time. With increasing the time to 60 min, the sheet resistance reaches the lowest desirable value of $132.2 \Omega \text{ sq}^{-1}$. However, the transmittance value also drops below 80%. To maintain a higher transmittance, a moderate

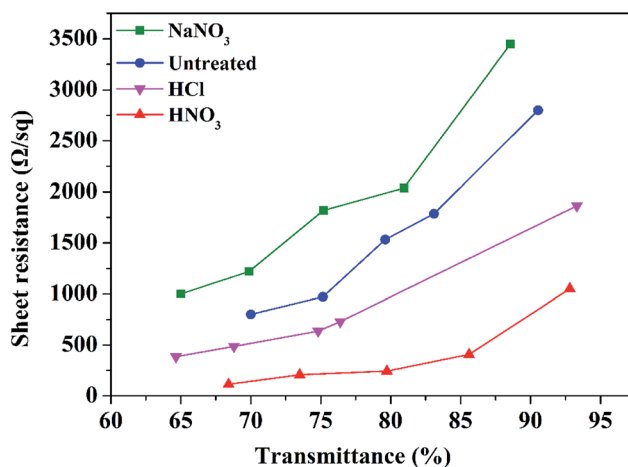


Fig. 1 The sheet resistance and transmittance of CNT-TCFs post-treated by different reagents.



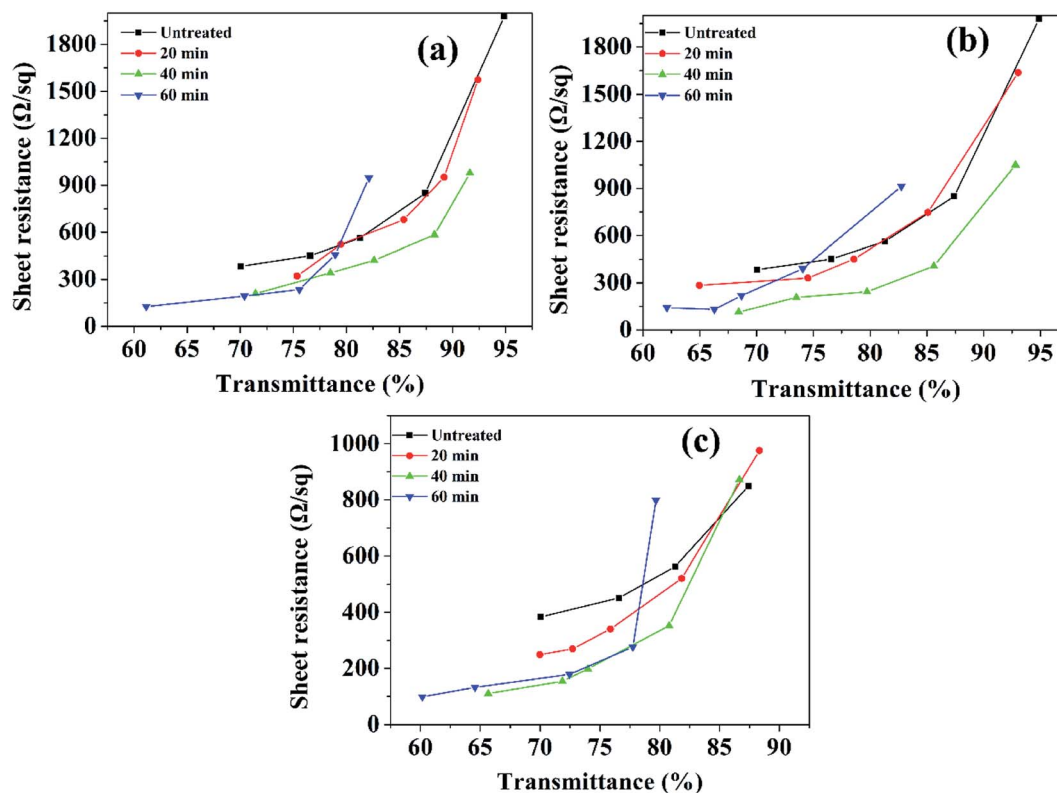


Fig. 2 The sheet resistance and transmittance of the CNT-TCFs treated by HNO_3 for a time from 0, 20, 40, to 60 min with different ratios of HNO_3 to water from (a) 4 : 1, (b) 6 : 1, and to (c) 8 : 1.

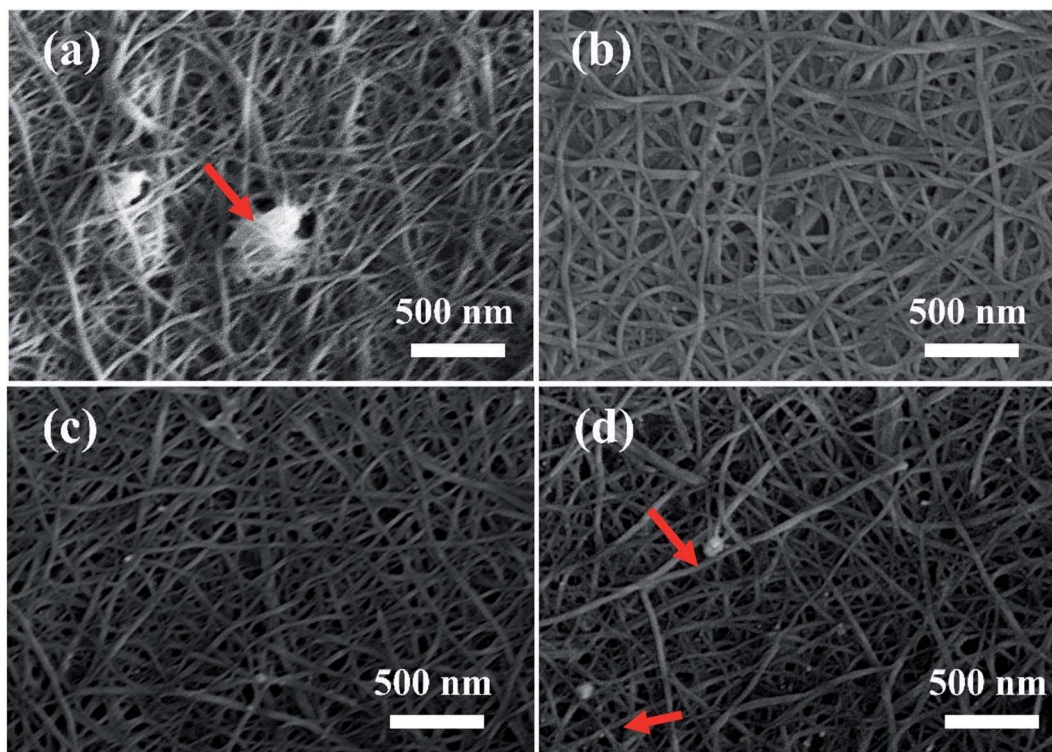


Fig. 3 SEM images of CNT-TCFs treated by different methods (a) untreated and treated by (b) HNO_3 , (c) HCl , and (d) NaNO_3 .



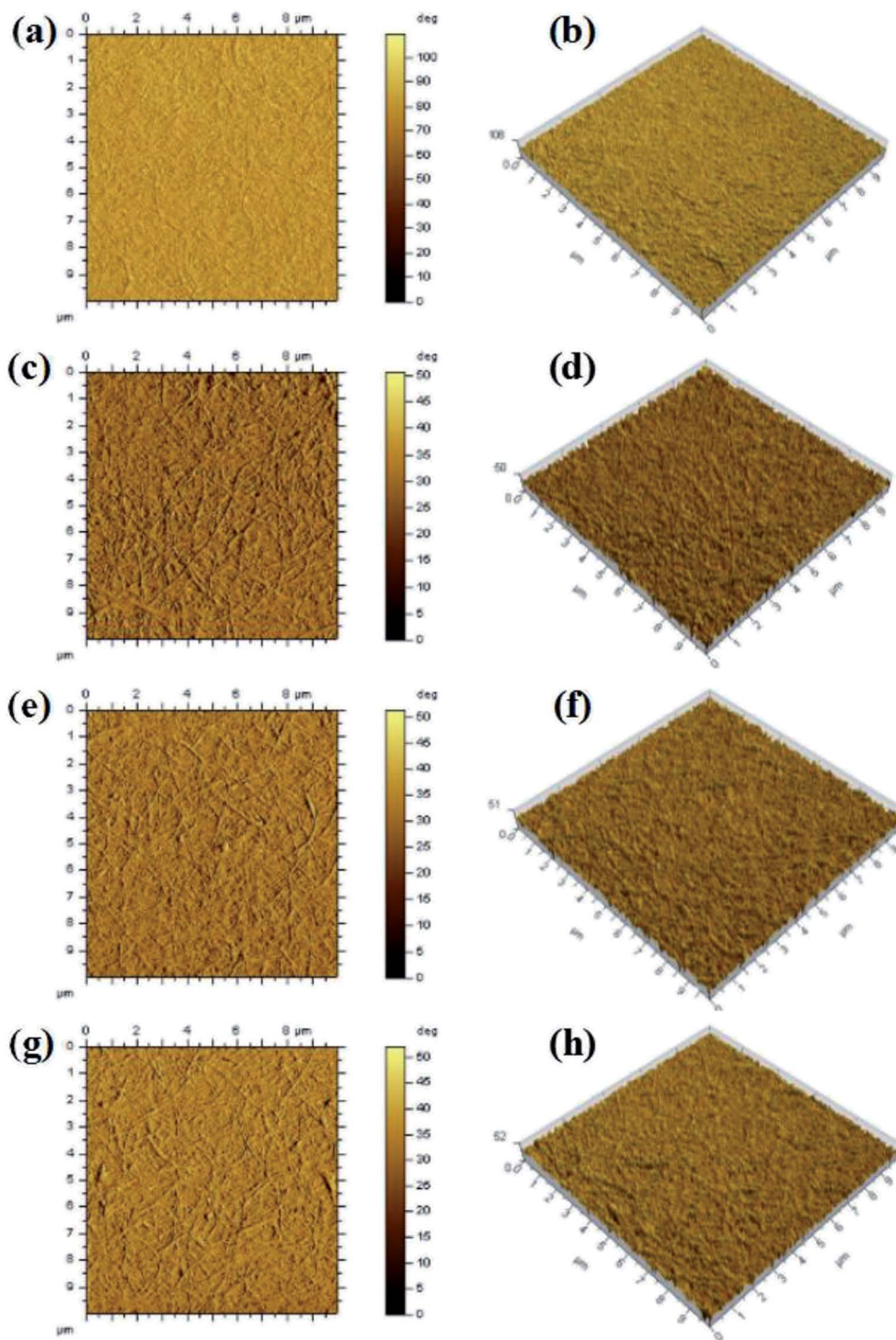


Fig. 4 AFM two and three dimensional phase images of untreated CNT-TCFs (a and b), and CNT-TCFs treated by HNO_3 (c and d), HCl (e and f), and NaNO_3 (g and h), respectively.

condition for post-treating TCFs is necessary. The results show that both parameters of sheet resistance and transmittance become acceptable, as the treating time is set as 40 min. Fig. 2 also shows a similar effect of the ratio of acid to water on the film properties. With increasing the HNO_3 content, the sheet resistance/transmittance declines/goes up simultaneously. A desirable condition was found for the ratio of acid to water as

6 : 1 where the sheet resistance is below $500 \Omega \text{ sq}^{-1}$ and transmittance is about 85%.

3.3 Surface morphology of films affected by different reagents during post-treatment

To reveal the effect of surface morphologies on the performance of CNT-TCFs, the CNT-TCFs treated by HNO_3 , HCl and NaNO_3



Table 1 AFM roughness parameters of the CNT-TCFs treated by different reagents^a

| | Untreated | Treated by HNO ₃ | Treated by HCl | Treated by NaNO ₃ |
|---------------------|-----------|-----------------------------|----------------|------------------------------|
| S _a (nm) | 28.9 | 25.5 | 26.7 | 27.5 |
| S _q (nm) | 33.0 | 31.0 | 31.1 | 31.5 |
| S _z (nm) | 89.0 | 87.3 | 90.0 | 93.3 |

^a S_a (nm): roughness average, S_q (nm): root mean square roughness, S_z (nm): ten-point height.

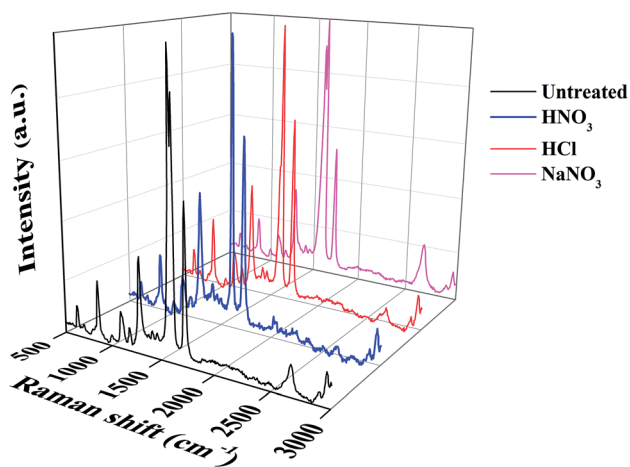


Fig. 5 Raman spectra (at 532 nm) of the untreated ($I_D/I_G \sim 0.30$) CNT-TCFs, and CNT-TCFs treated by HNO₃ ($I_D/I_G \sim 0.41$), HCl ($I_D/I_G \sim 0.39$) and NaNO₃ ($I_D/I_G \sim 0.31$), respectively.

are imaged by FE-SEM and shown in Fig. 3. The CNT-TCFs without treatment and CNT-TCFs treated by a saturated solution of NaNO₃ have residual SDBS inside the CNT network, which definitely impedes the film conductivity. Whereas, for the CNT-TCFs treated with two acids, little residual SDBS can be found. CNTs are homogeneously distributed on the film surface. From this we can know that the strong acidity of nitric acid removes residual SDBS.

3.4 Surface topology and roughness of CNT-TCFs treated by different reagents during post-treatment

The AFM images of the surface topology for CNT-TCFs are shown in Fig. 4 and Table 1. The root mean square roughness values of untreated CNT-TCFs and CNT-TCFs treated with HNO₃, HCl, and NaNO₃ were 33.0 nm, 31.0 nm, 31.1 nm, and 31.5 nm, respectively. We assume that the SDBS particles on the CNT-TCF surface were removed during the post-treatment process. As seen from the diagram, the surface roughness of the film is reduced after nitric acid treatment. This is beneficial to its application in the transparent electrode field.

3.5 Characterization of the CNT-TCFs by Raman spectra and XPS

Raman spectra were carried out to characterize the change of CNTs in the CNT-TCFs with an excitation laser wavelength of 532 nm (2.33 eV). As shown in Fig. 5, the D peak near 1280 cm⁻¹ is a reflection of the defects and disorder in CNTs whereas the G peak near 1580 cm⁻¹ represents the order of the CNTs.^{23,24} The ratio of I_D/I_G reflects the degree of disorder and defects in the sample. Here the change of I_D/I_G can also reflect the degree of surface functionalization.²⁵ As can be calculated from Fig. 5, the I_D/I_G ratio of the film treated by NaNO₃ (0.31) is little changed as compared to that of the untreated CNT-TCFs (0.30), indicating that the CNT surface structure has not been changed a lot by NaNO₃. An increase in the I_D/I_G ratio was found for the CNT-TCFs treated by acid solution, and the I_D/I_G value for HNO₃ treated CNT-TCFs (0.41) is higher than that for HCl treated CNT-TCFs (0.39). This suggests that chemical oxidation might actually occur and result in detachment of the surfactant from the CNT surface, and eventually lower the sheet resistance.²⁶

XPS analysis was used to provide information about element contents present in the CNT-TCFs after being treated by three different reagents, as shown in Fig. 6. As shown in Fig. 6a, a similar height of the S2p peaks appears in the three samples of untreated TCFs and TCFs treated by HCl and NaNO₃. The sulfur content of the CNT-TCFs treated with HCl and NaNO₃ did not decrease significantly, indicating that SDBS still has some residues. The weakest S2p signal was found for the sample after

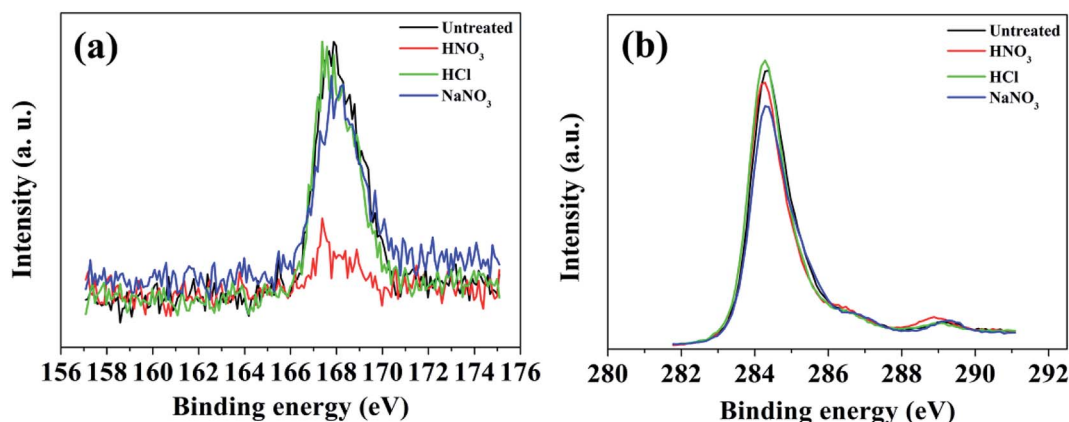


Fig. 6 XPS S2p (a) and C1s (b) spectra of untreated TCFs and TCFs treated by HNO₃, HCl, and NaNO₃, respectively.



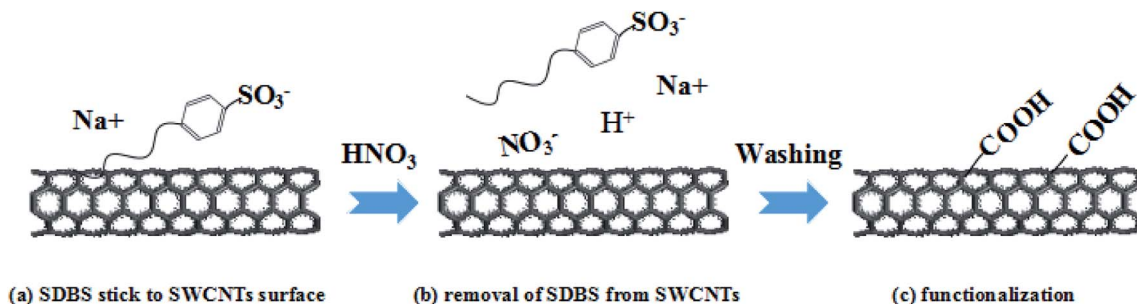


Fig. 7 Mechanism of reducing the surface resistance of CNT-TCFs after HNO_3 treatment.

treatment with HNO_3 , which also explains the effectivity of HNO_3 treatment. In comparison with the untreated CNT-TCFs, a shift of 2 eV binding energy in the C1s spectra was found in TCFs treated by HCl and NaNO_3 , whereas, a shift of 4 eV binding energy in the C1s spectra was found for the HNO_3 treated TCFs, as shown in Fig. 6b. This also proved that CNTs underwent a certain extent of chemical oxidation due to HNO_3 post-treatment. In general, the HNO_3 treatment results in a decrease in the sheet resistance of the CNT-TCFs due to the combined effect of acidity and oxidizability. The strong interaction of the strong acidity and strong oxidizing property of nitric acid causes the SDBS to be removed. At the same time, strong oxidation makes the surface of the CNTs to some extent oxidized.

The Raman and XPS results clearly prove that oxidation happens during the film treatment by HNO_3 . Therefore, a schematic description of the mechanism is shown in Fig. 7. It is speculated that during the acid treatment process, NO_3^- and H^+ in HNO_3 remove the SDBS due to their strong interaction with the CNT surface and eventually lead to oxidization. The subsequent water-washing step is to wash away the residual HNO_3 and the small amount of SDBS on the CNT-TCFs, hence reducing the contact resistance among the CNTs, resulting in a significant reduction in the sheet resistance of the CNT-TCFs.

4. Conclusions

In this study, CNT-TCFs were post-treated by three different reagents for a better understanding of the effect of post-treatment by HNO_3 , a mechanism of the post-treating process was proposed. By optimizing the experimental conditions, we found that the desired electronic properties of the CNT-TCFs can be achieved under a treatment time of 40 min and with a ratio of nitric acid to water of 6 : 1. Both SEM and AFM analysis show that the TCFs after being post-treated by HNO_3 have a homogenous surface and minimum surface roughness. The comparison studies show that the CNT-TCFs treated by HNO_3 possess the best optoelectronic properties with higher transmittance and lower sheet resistance. The reason is because of the oxidation effect and acidity co-existing during post-treatment by HNO_3 . The strong interaction of the strong acidity and strong oxidizing property of HNO_3 causes the SDBS to be removed. At the same time, strong oxidation makes the

surface of the CNTs to some extent oxidized. Conclusively, this work reveals that HNO_3 treatment can effectively remove the residue of surfactants and improve the CNT-TCFs' properties through an oxidization effect, which significantly advances the understanding in related fields.

Conflicts of interest

There are no conflicts to declare.

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